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June 2009

FDV301N Digital FET, N-Channel

General Description

This N-Channel logic level enhancement mode field effect transistor is produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance. This device has been designed especially for low voltage applications as a replacement for digital transistors. Since bias resistors are not required, this one N-channel FET can replace several different digital transistors, with different bias resistor values.

Features

■ 25 V, 0.22 A continuous, 0.5 A Peak.

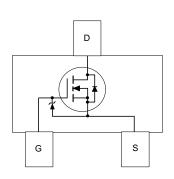
$$\begin{split} R_{\text{DS(ON)}} &= 5~\Omega~@~\text{V}_{\text{GS}} \text{= 2.7 V} \\ R_{\text{DS(ON)}} &= 4~\Omega~@~\text{V}_{\text{GS}} \text{= 4.5 V}. \end{split}$$

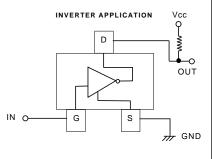
- Very low level gate drive requirements allowing direct operation in 3V circuits. $V_{GS(th)} < 1.06V$.
- Gate-Source Zener for ESD ruggedness. >6kV Human Body Model
- Replace multiple NPN digital transistors with one DMOS



Mark:301







Absolute Maximum Ratings $T_A = 25^{\circ}C$ unless other wise noted

Symbol	Parameter	FDV301N	
Cyllibol	1 diameter	1 5 7 30 114	Units
$V_{\rm DSS}$, $V_{\rm CC}$	Drain-Source Voltage, Power Supply Voltage	25	V
V_{GSS} , V_{I}	Gate-Source Voltage, V _{IN}	8	V
I _D , I _O	Drain/Output Current - Continuous	0.22	А
		0.5	
P _D	Maximum Power Dissipation	0.35	W
T _J ,T _{STG}	Operating and Storage Temperature Range	-55 to 150	℃
ESD Electrostatic Discharge Rating MIL-STD-883D Human Body Model (100pf / 1500 Ohm)		6.0	kV
THERMAI	CHARACTERISTICS		
R _{gJA} Thermal Resistance, Junction-to-Ambient		357	°C/W

Inverter Electrical Characteristics (T _A = 25 °C unless otherwise noted)						
Symbol	Parameter	Conditions	Min	Тур	Max	Units
I _{O (off)}	Zero Input Voltage Output Current	$V_{CC} = 20 \text{ V}, \ V_{I} = 0 \text{ V}$			1	μA
V _{I (off)}	Input Voltage	$V_{CC} = 5 \text{ V}, I_{O} = 10 \mu\text{A}$			0.5	V
V _{I (on)}		$V_0 = 0.3 \text{ V}, I_0 = 0.005 \text{ A}$	1			V
R _{o (on)}	Output to Ground Resistance	$V_1 = 2.7 \text{ V}, \ I_0 = 0.2 \text{ A}$		4	5	Ω

Electrical Characteristics ($T_A = 25$ $^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHARA	ACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$		25			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_D = 250 \mu\text{A}$, Referenced to 2	5°C		25		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 20 \text{ V}, \ V_{GS} = 0 \text{ V}$				1	μΑ
			T _J = 55°C			10	μA
I _{GSS}	Gate - Body Leakage Current	$V_{GS} = 8 \text{ V}, \ V_{DS} = 0 \text{ V}$				100	nA
ON CHARAC	TERISTICS (Note)	·					
$\Delta V_{GS(th)}/\Delta T_{J}$	Gate Threshold Voltage Temp. Coefficient	$I_D = 250 \mu\text{A}$, Referenced to 2	5°C		-2.1		mV/°C
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$		0.70	0.85	1.06	V
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = 2.7 \text{ V}, I_D = 0.2 \text{ A}$			3.8	5	Ω
			T _J =125°C		6.3	9	
		$V_{GS} = 4.5 \text{ V}, I_D = 0.4 \text{ A}$			3.1	4	
I _{D(ON)}	On-State Drain Current	$V_{GS} = 2.7 \text{ V}, \ V_{DS} = 5 \text{ V}$		0.2			Α
9 _{FS}	Forward Transconductance	$V_{DS} = 5 \text{ V}, I_{D} = 0.4 \text{ A}$			0.2		S
DYNAMIC CH	HARACTERISTICS	·					
C _{iss}	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz			9.5		pF
C _{oss}	Output Capacitance				6		pF
C _{rss}	Reverse Transfer Capacitance				1.3		pF
SWITCHING	CHARACTERISTICS (Note)						
t _{D(on)}	Turn - On Delay Time	$V_{DD} = 6 \text{ V}, I_{D} = 0.5 \text{ A},$			3.2	8	ns
t,	Turn - On Rise Time	$V_{GS} = 4.5 \text{ V}, R_{GEN} = 50 \Omega$	$V_{GS} = 4.5 \text{ V}, R_{GEN} = 50 \Omega$		6	15	ns
t _{D(off)}	Turn - Off Delay Time				3.5	8	ns
t _f	Turn - Off Fall Time				3.5	8	ns
Q_g	Total Gate Charge	$V_{DS} = 5 \text{ V}, I_{D} = 0.2 \text{ A},$ $V_{GS} = 4.5 \text{ V}$			0.49	0.7	nC
Q_{gs}	Gate-Source Charge				0.22		nC
Q_{gd}	Gate-Drain Charge				0.07		nC
DRAIN-SOUP	RCE DIODE CHARACTERISTICS AND MAXIMU	JM RATINGS					
Is	Maximum Continuous Drain-Source Diode For	rward Current				0.29	А
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 0.29 \text{ A}$ (Note)			0.8	1.2	V
	1	•					

Note:
Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2.0%.

Typical Electrical Characteristics

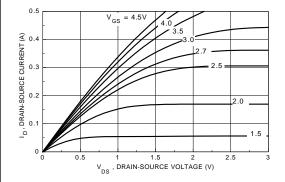


Figure 1. On-Region Characteristics.

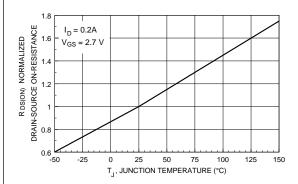


Figure 3. On-Resistance Variation with Temperature.

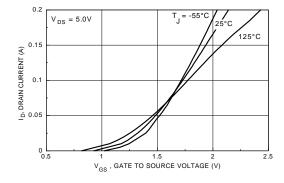


Figure 5. Transfer Characteristics.

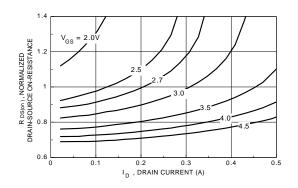


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

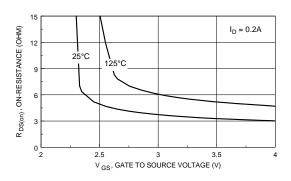


Figure 4. On Resistance Variation with Gate-To-Source Voltage.

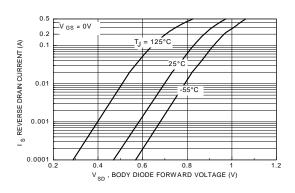


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Electrical And Thermal Characteristics

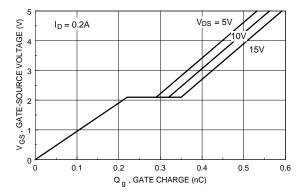


Figure 7. Gate Charge Characteristics.

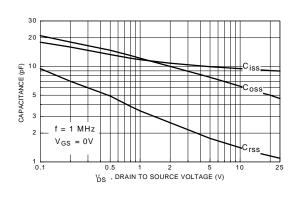


Figure 8. Capacitance Characteristics.

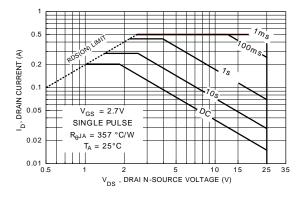


Figure 9. Maximum Safe Operating Area.

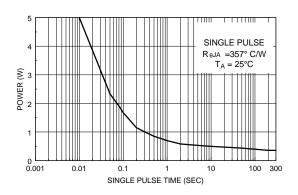


Figure 10. Single Pulse Maximum Power Dissipation.

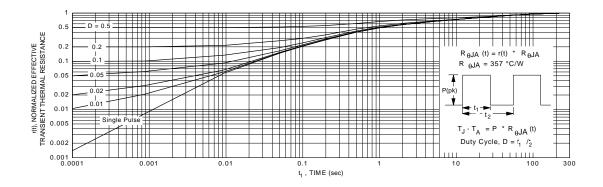


Figure 11. Transient Thermal Response Curve.





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